



DATA SHEET

PHOTOCOUPLER PS9634, PS9634L

POWER TRANSISTOR DRIVING BASE AMPLIFIER BUILT-IN TYPE PHOTOCOUPLER

DESCRIPTION

The PS9634 and PS9634L are optical linkage devices mounting a GaAs infrared ray LED on the light emitting side (input side) and a photo diode and a signal processing circuit on the light receiving side (output side) on one chip.

They can directly drive a power transistor of 15 to 20 A class used for such as an inverter control air conditioner or general purpose inverter.

The PS9634L has a surface mount type lead.

FEATURES

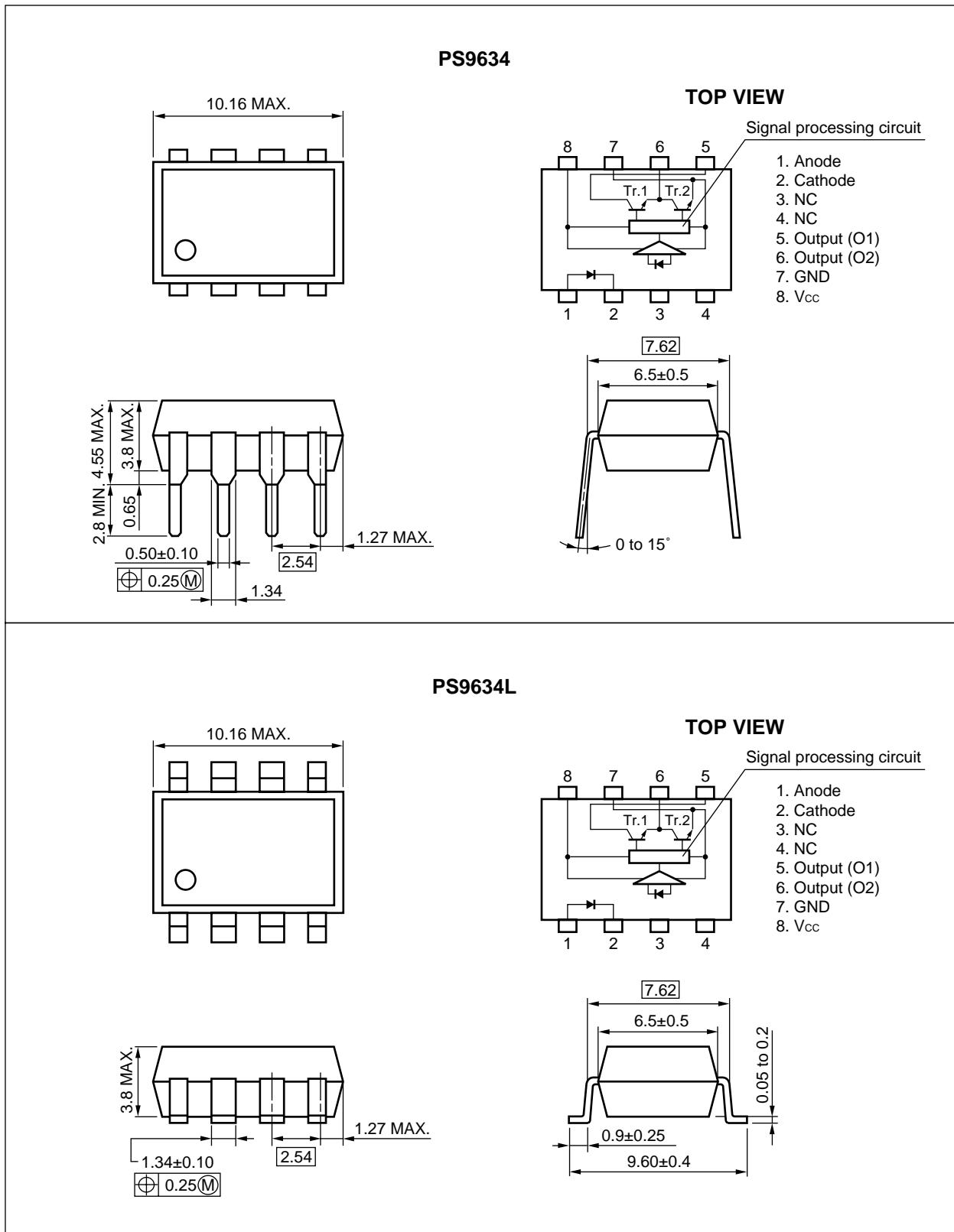
- High instantaneous common mode rejection voltage ($CMH = -1\ 000\ V/\mu s$ MIN., $CML = 1\ 000\ V/\mu s$ MIN.)
- High supply voltage ($Vcc = 18\ V$)
- High-speed response ($t_{PHL}, t_{PLH} = 5\ \mu s$ MAX.)
- High output current ($I_{O1} = 0.5\ A$ (DC), $I_{O1P} = 1.0\ A$ (pulse))
- Taping product name (PS9634L-E3, E4)

APPLICATIONS

- Inverter control air conditioner
- General purpose inverter

The information in this document is subject to change without notice.

★ PACKAGE DIMENSIONS (in millimeters)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I_F	30	mA
	Reverse Voltage	V_R	6.0	V
	Peak Forward Current ^{*1}	I_{FM}	1	A
Detector	Supply Voltage	V_{CC}	18	V
	Output Current (O1)	I_{O1}	0.5	A
	Peak Output Current (O1)	I_{O1P}	1.0	
	Output Current (O2)	I_{O2}	0.8	
	Peak Output Current (O2)	I_{O2P}	2.0	
	Output Voltage (O1)	V_{O1}	18	V
	Power Dissipation	P_o	500	mW
Isolation Voltage ^{*2}		BV	5 000	Vr.m.s.
Total Power Dissipation		P_T	550	mW
Operating Ambient Temperature		T_A	-20 to +80	°C
Storage Temperature		T_{STG}	-55 to +150	°C

^{*1} PW = 100 μs , Duty Cycle = 1 %^{*2} AC voltage for 1 minute at $T_A = 25^\circ\text{C}$, RH = 60 % between input and output**RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Input On Current	I_{FLH}	6	8	10	mA
Supply Voltage	V_{CC}	5.4		15	V
Output Current (O1)	I_{O1}	0.1	0.2	0.3	A
Output Current (O2)	I_{O2}				
Operating Ambient Temperature	T_A	0	25	50	°C

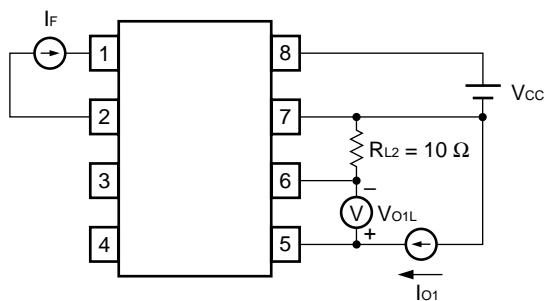
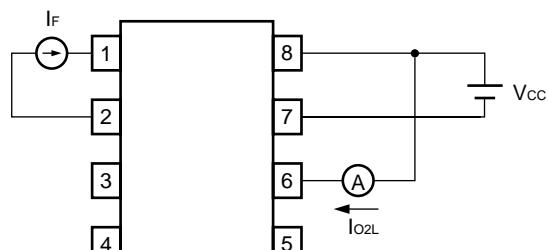
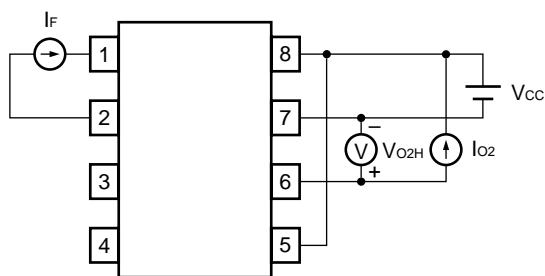
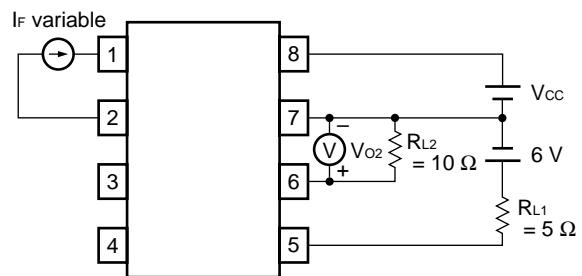
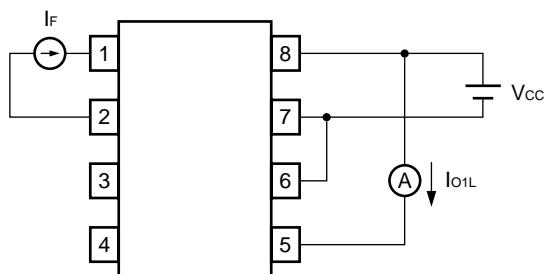
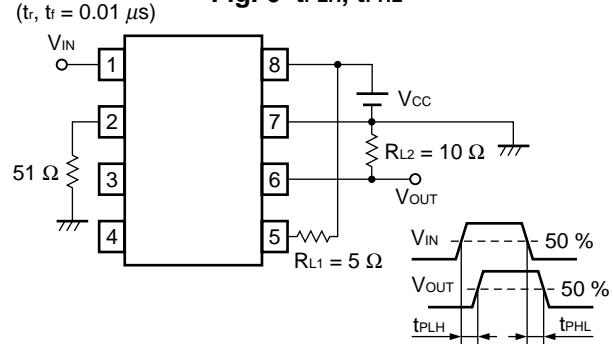
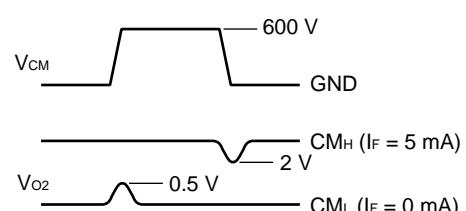
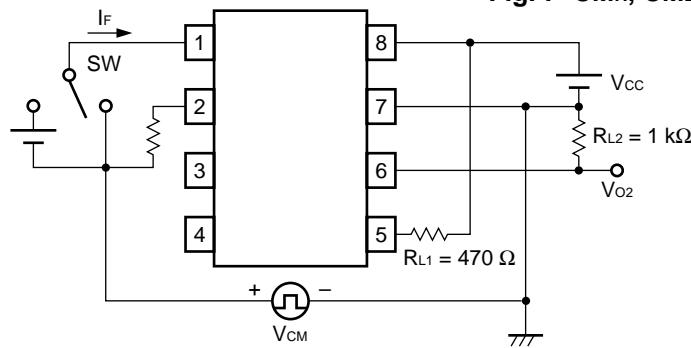
TRUTH TABLE

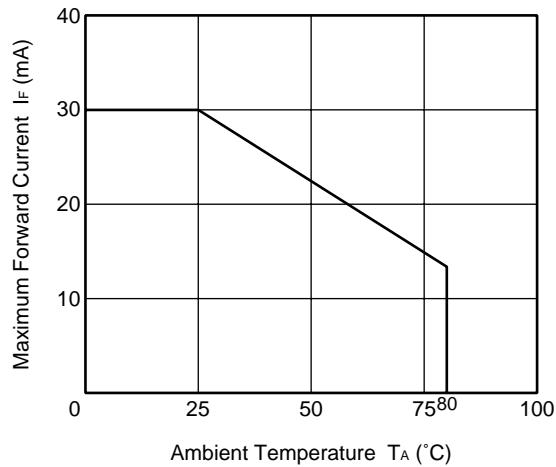
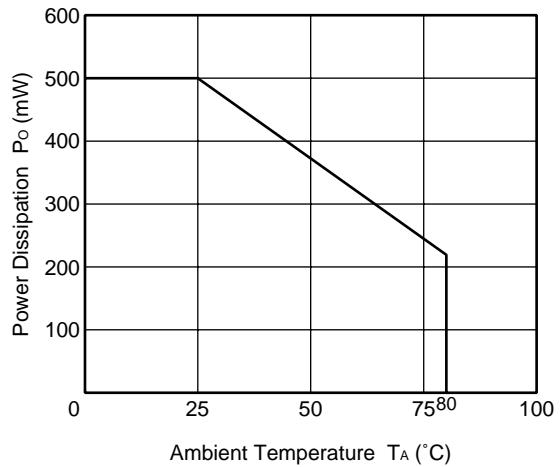
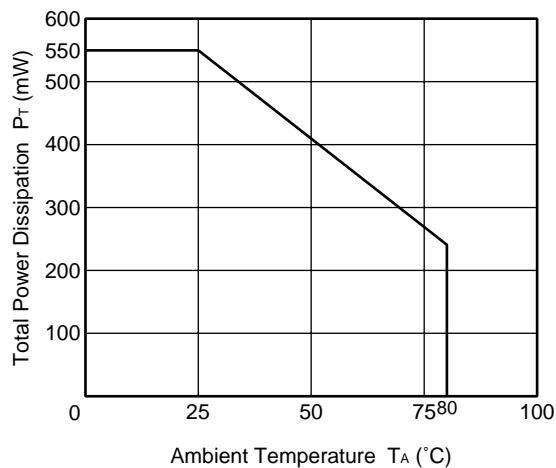
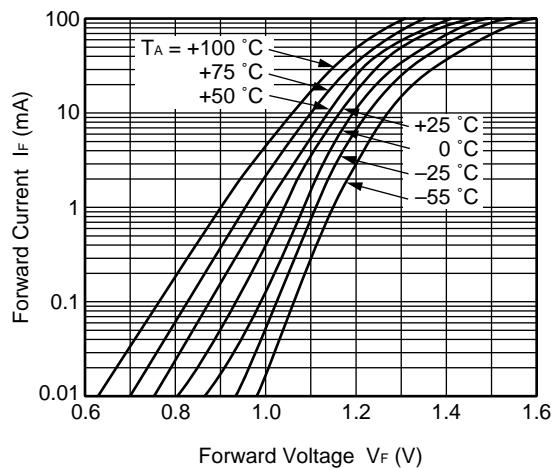
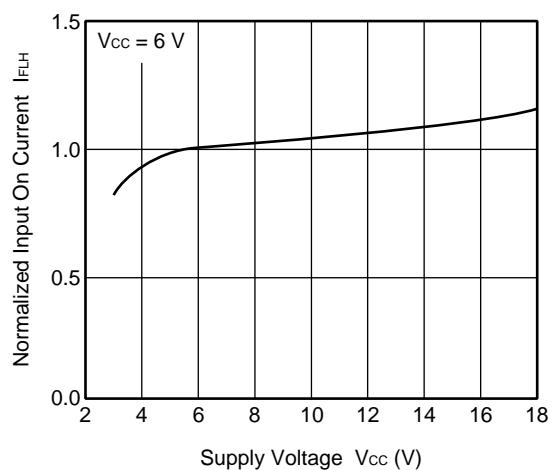
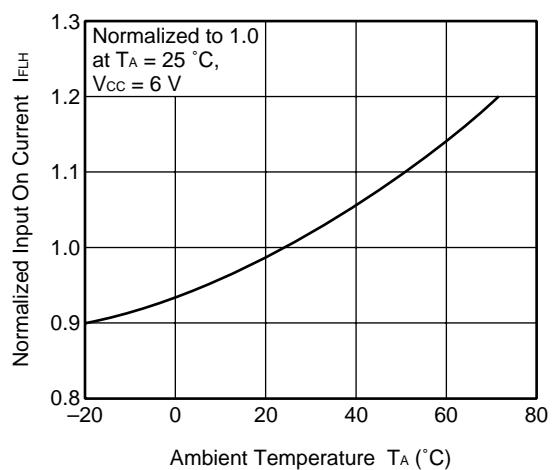
	LED	
	ON	OFF
Tr. 1	ON	OFF
Tr. 2	OFF	ON

ELECTRICAL CHARACTERISTICS ($T_A = -20$ to $+80$ °C, unless otherwise specified)

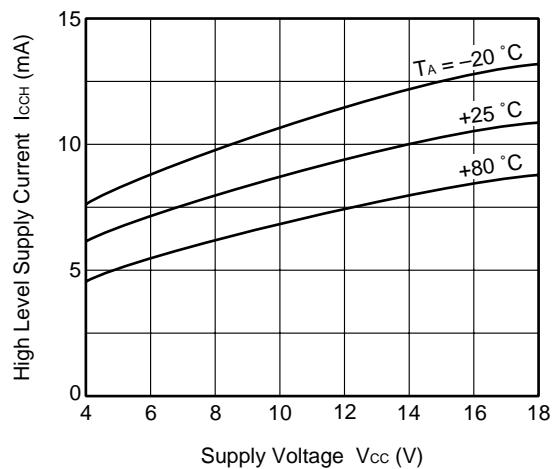
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Fig.
Diode	Forward Voltage	V_F	$I_F = 5$ mA, $T_A = 25$ °C		1.1	1.4	V	
	Reverse Current	I_R	$V_R = 5$ V, $T_A = 25$ °C			5	μ A	
	Terminal Capacitance	C_t	$V = 0$ V, $f = 1.0$ MHz, $T_A = 25$ °C		30		pF	
Detector	Supply Voltage	V_{CC}		5.4		15	V	
	Low Level Output Voltage (O1)	V_{O1L}	$V_{CC} = 6$ V, $I_{O1} = 0.4$ A, $R_{L2} = 10$ Ω, $I_F = 5$ mA		0.25	0.40	V	1
	High Level Output Voltage (O2)	V_{O2H}	$V_{CC} = 6$ V, $I_{O2} = -0.4$ A, $I_F = 5$ mA	4.5	5.0		V	2
	Low Level Output Voltage (O2)	V_{O2L}	$V_{CC} = 6$ V, $I_{O2} = 0.5$ A, $I_F = 0$ mA		0.25	0.40	V	
	Leakage Current (O1)	I_{O1L}	$V_{CC} = 13$ V, $I_F = 0$ mA			100	μ A	3
	Leakage Current (O2)	I_{O2L}	$V_{CC} = 13$ V, $I_F = 5$ mA			100	μ A	4
	High Level Supply Current	I_{CCH}	$T_A = 25$ °C $V_{CC} = 6$ V, $I_F = 5$ mA		8	12	mA	
	Low Level Supply Current	I_{CCL}	$T_A = 25$ °C $V_{CC} = 6$ V, $I_F = 0$ mA		15	18	mA	
Coupled	Input On Current ($L \rightarrow H$)	I_{FLH}	$T_A = 25$ °C $V_{CC} = 6$ V, $R_{L1} = 5$ Ω, $R_{L2} = 10$ Ω	0.3 0.2	1.5	3.0 5.0	mA	5
	Isolation Resistance	R_{I-O}	$R_H = 40$ to 60 %, $T_A = 25$ °C	10^{11}			Ω	
	Propagation Delay Time ($L \rightarrow H$)	t_{PLH}	$V_{CC} = 6$ V, $I_F = 5$ mA, $T_A = 25$ °C $R_{L1} = 5$ Ω, $R_{L2} = 10$ Ω		3	5	μ s	6
	Propagation Delay Time ($H \rightarrow L$)	t_{PHL}						
	Instantaneous Common Mode Rejection Voltage (Output: High)	CM_H	$T_A = 25$ °C, $V_{CM} = 600$ V (peak), $I_F = 5$ mA, $R_{L1} = 470$ Ω, $R_{L2} = 1$ kΩ, $\Delta V_{O2H} = 2$ V	-1 000			V/ μ s	7
	Instantaneous Common Mode Rejection Voltage (Output: Low)	CM_L	$T_A = 25$ °C, $V_{CM} = 600$ V (peak), $I_F = 0$ mA, $R_{L1} = 470$ Ω, $R_{L2} = 1$ kΩ, $\Delta V_{O2L} = 0.5$ V	1 000			V/ μ s	

MEASUREMENT CIRCUITS FOR ELECTRICAL CHARACTERISTICS

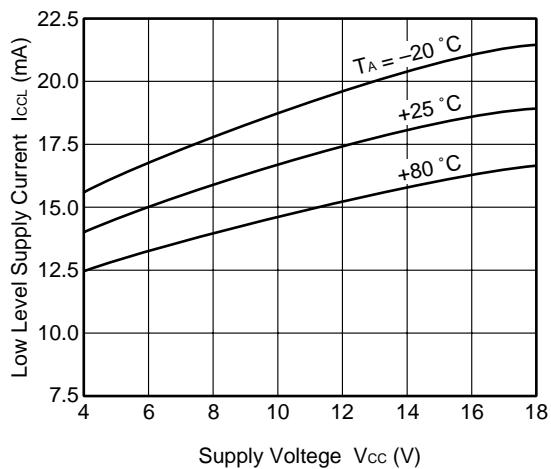
Fig. 1 V_{O1L} **Fig. 4** I_{O2L} **Fig. 2** V_{O2H} **Fig. 5** I_{FLH} **Fig. 3** I_{O1L} **Fig. 6** t_{PLH}, t_{PHL} **Fig. 7** C_{MH}, C_{ML} 

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)**MAXIMUM FORWARD CURRENT vs.
AMBIENT TEMPERATURE****POWER DISSIPATION vs.
AMBIENT TEMPERATURE****TOTAL POWER DISSIPATION vs.
AMBIENT TEMPERATURE****FORWARD CURRENT vs.
FORWARD VOLTAGE****NORMALIZED INPUT ON CURRENT vs.
SUPPLY VOLTAGE****NORMALIZED INPUT ON CURRENT vs.
AMBIENT TEMPERATURE**

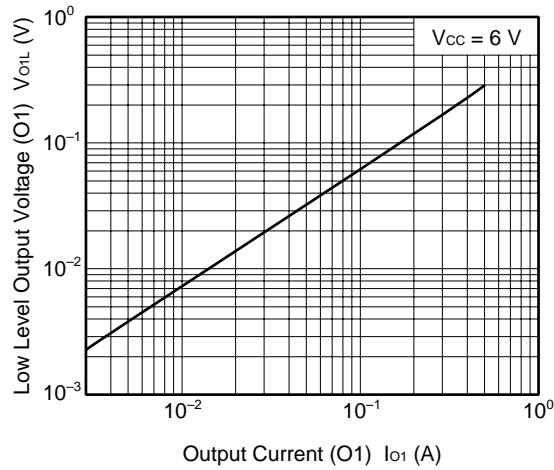
HIGH LEVEL SUPPLY CURRENT vs.
SUPPLY VOLTAGE



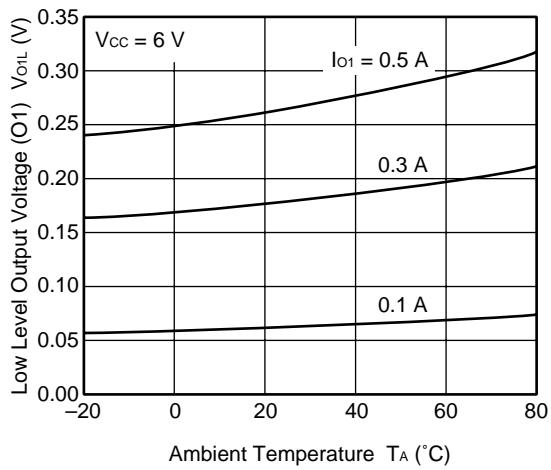
LOW LEVEL SUPPLY CURRENT vs.
SUPPLY VOLTAGE



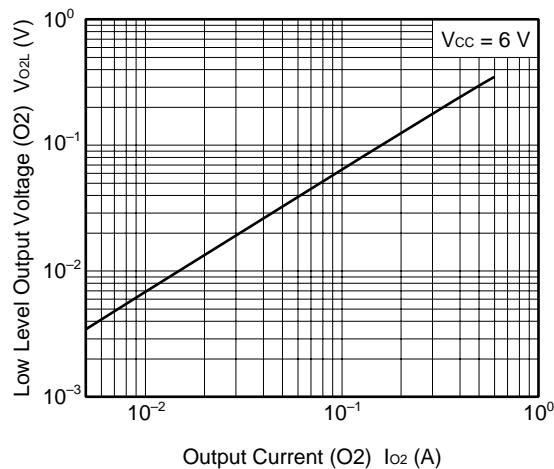
LOW LEVEL OUTPUT VOLTAGE (O1)
vs. OUTPUT CURRENT (I_{O1})



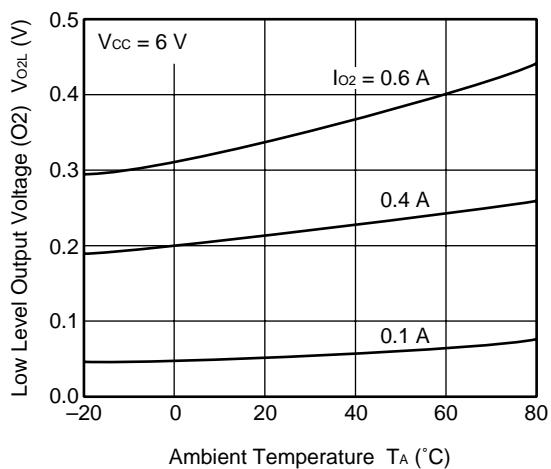
LOW LEVEL OUTPUT VOLTAGE (O1)
vs. AMBIENT TEMPERATURE



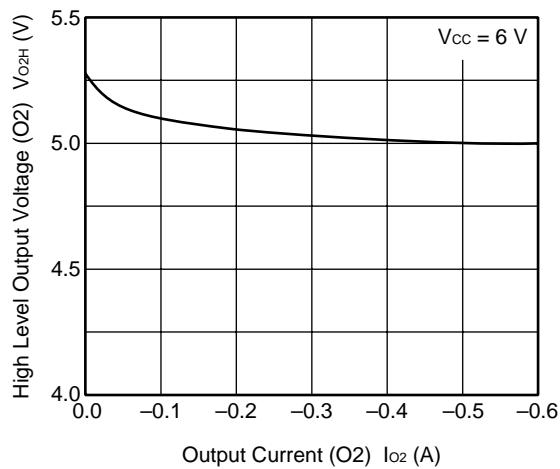
LOW LEVEL OUTPUT VOLTAGE (O2)
vs. OUTPUT CURRENT (I_{O2})



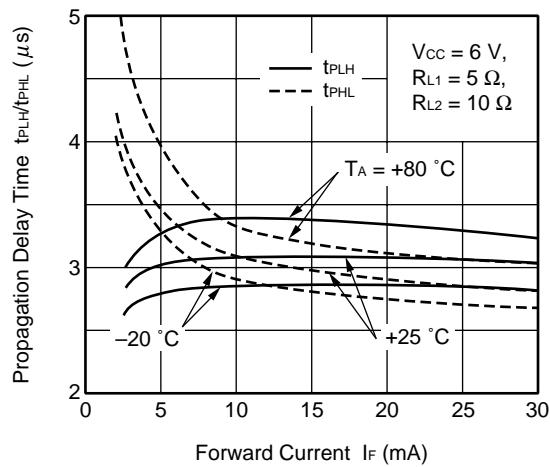
LOW LEVEL OUTPUT VOLTAGE (O2)
vs. AMBIENT TEMPERATURE



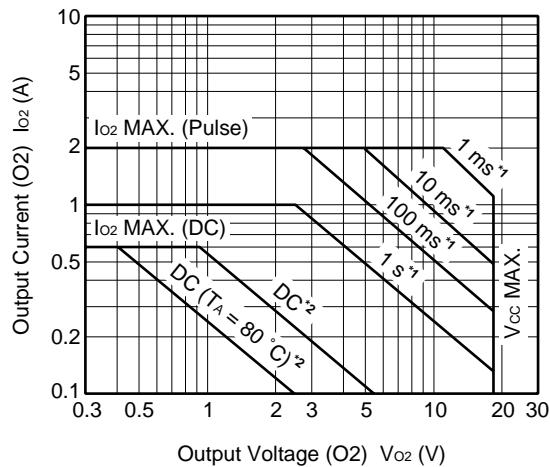
HIGH LEVEL OUTPUT VOLTAGE (O2) vs. OUTPUT CURRENT (O2)



PROPAGATION DELAY TIME vs. FORWARD CURRENT



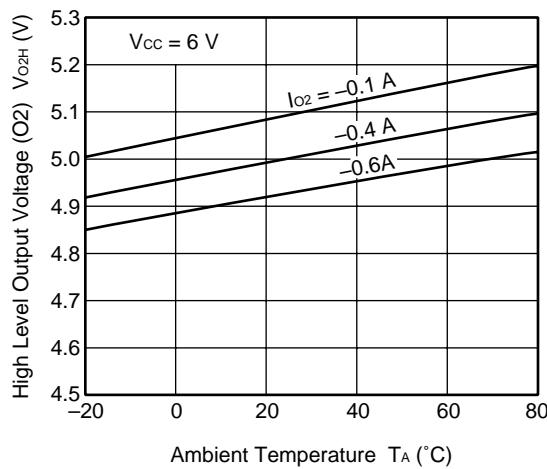
SAFE OPERATING AREA (Tr.1)



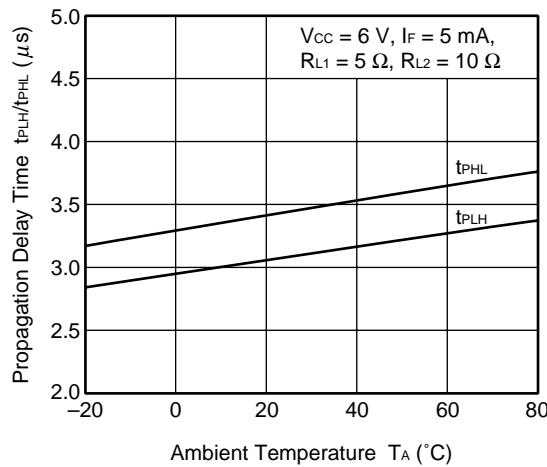
*1 One pulse

*2 On the epoxy board

HIGH LEVEL OUTPUT VOLTAGE (O2) vs. AMBIENT TEMPERATURE



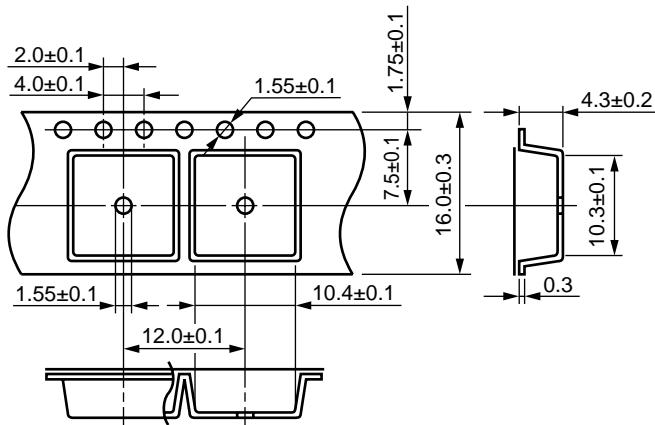
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



Remark The measurement of TYPICAL CHARACTERISTICS are only for reference, not guaranteed.

★ TAPING SPECIFICATIONS (in millimeters)

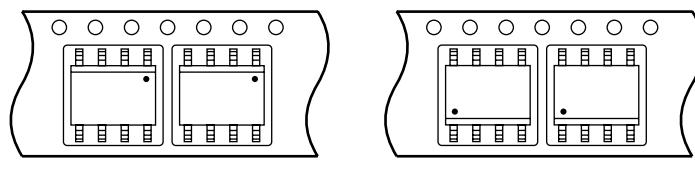
Outline and Dimensions (Tape)



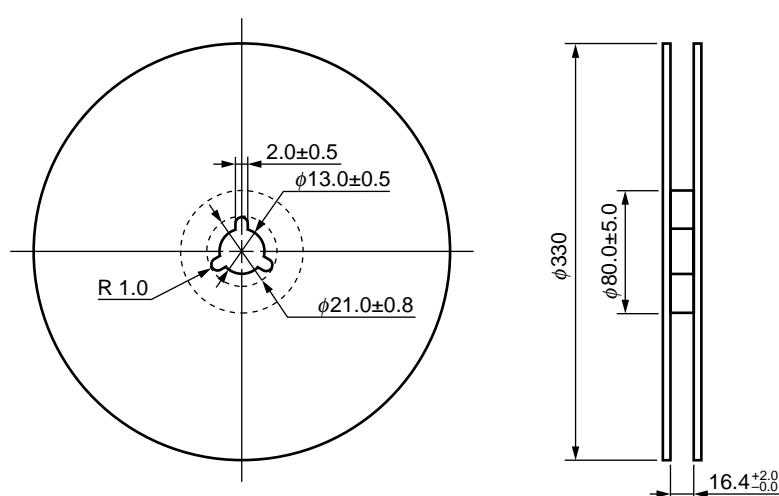
Tape Direction

PS9634L-E3

PS9634L-E4



Outline and Dimensions (Reel)



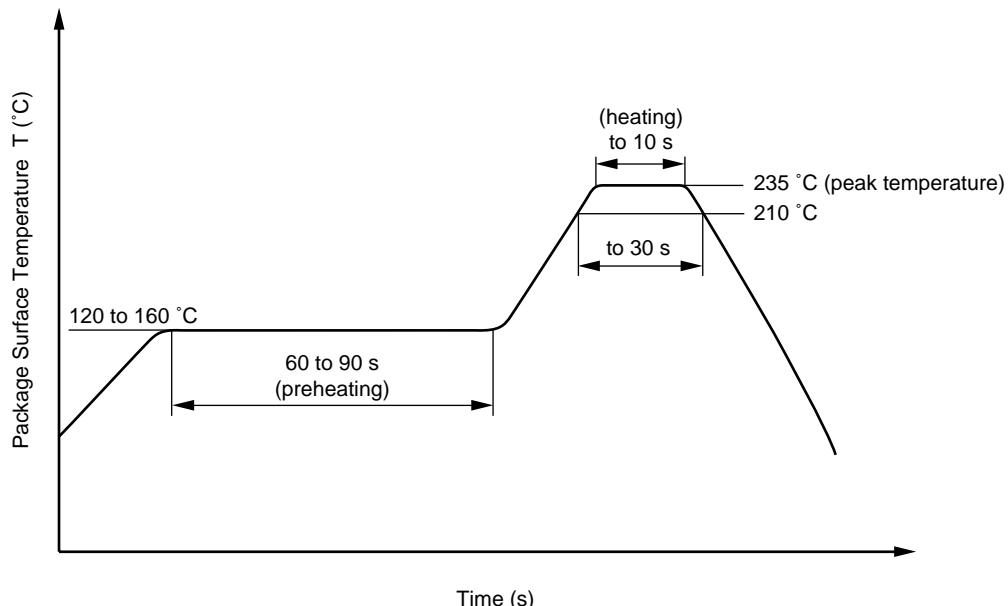
Packing: 1 000 pcs/reel

RECOMMENDED SOLDERING CONDITIONS

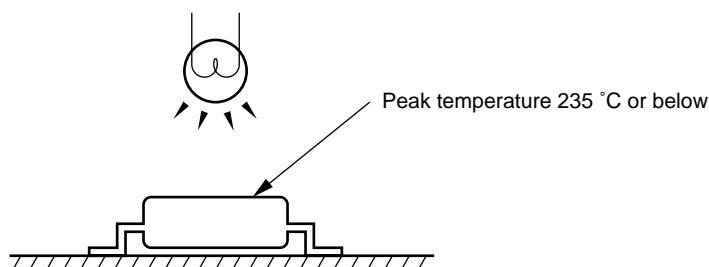
(1) Infrared reflow soldering

- Peak reflow temperature 235 °C (package surface temperature)
- Time of temperature higher than 210 °C 30 seconds or less
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



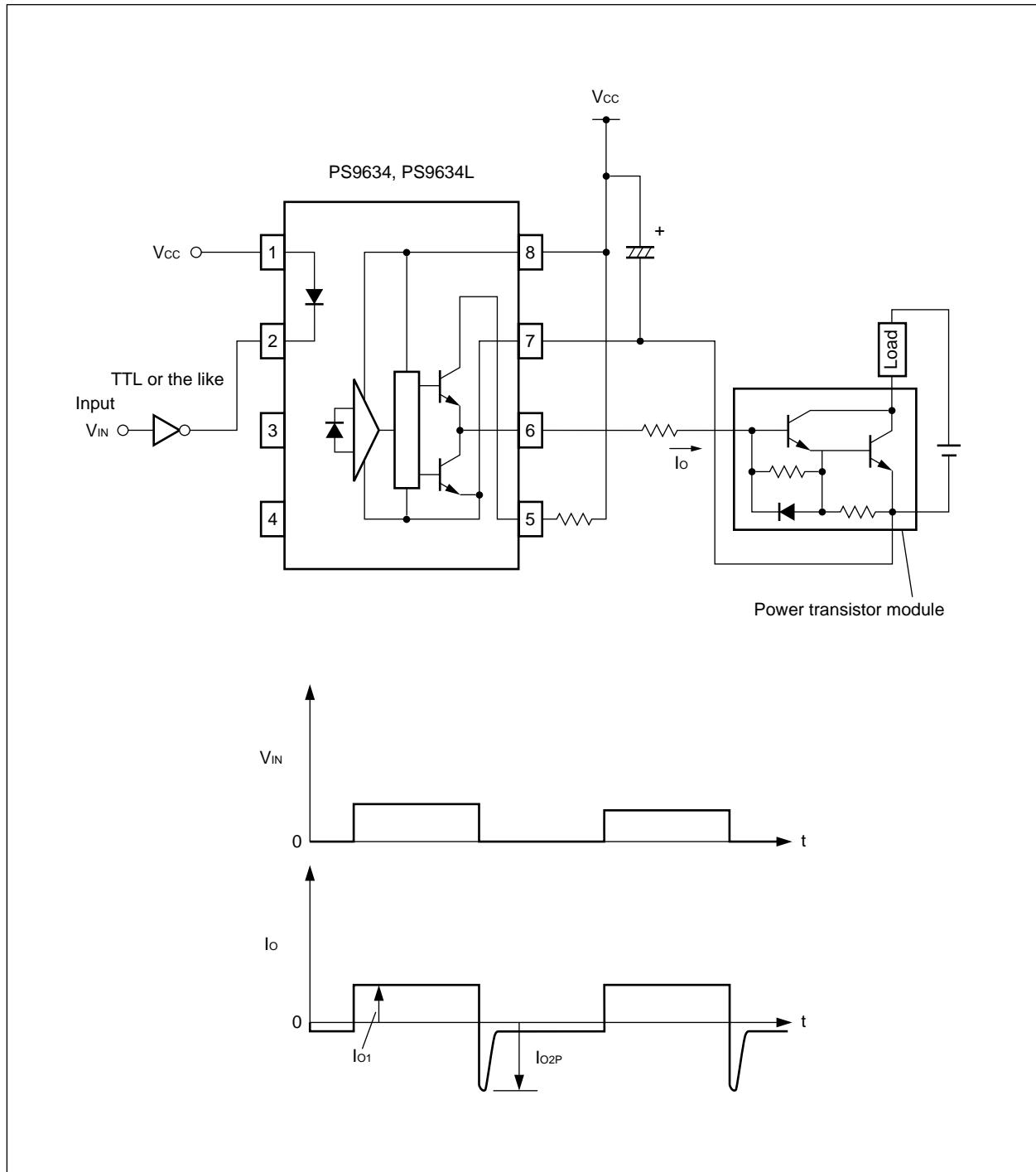
Caution Please avoid to removed the residual flux by water after the first reflow processes.



(2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Number of times One
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

APPLICATION EXAMPLE OF PHOTOCOUPLED (TO POWER TRANSISTOR MODULE)



CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.